

Vishay Siliconix

Low-Voltage, 0.4 Ω R_{ON}, Single SPST Analog Switch

DESCRIPTION

The DG2715, DG2716 are low voltage, single supply, dual SPST analog switches. Designed for high performance switching of analog signals, the DG2715/2716 provide low on-resistance (0.4 Ω at + 2.7 V), fast speed (t_{ON}, t_{OFF} at 17 ns and 14 ns) and the ability to handle signals over the entire analog voltage range.

When operated on a + 3 V supply, control pins are compatible with 1.8 V digital logic. Additionally, on-resistance flatness and matching (0.05 Ω and 0.1 Ω) offer high accuracy between channels.

Built on Vishay Siliconix's low voltage submicron CMOS process, the DG2715, DG2716 were designed to offer solutions that extend beyond audio/video functions, to providing the performance required for today's demanding mixed-signal switching in portable applications.

The DG2715 contains a normally open (NO) switch, and the DG2716 contains a normally closed switch. An epitaxial layer prevents latch-up. All switches conduct equally well in both directions when on, and block up to the power supply level when off.

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with the lead (Pb)-free device terminations. For analog switching products manufactured with 100 % matte tin device terminations, the lead (Pb)-free "-E3" suffix is being used as a designator.

FEATURES

- Low voltage operation (1.6 V to 3.6 V)
- Low on-resistance R_{DS(on)}: 0.4 Ω at 2.7 V
- Off-isolation: 57 dB at 1 MHz
- Fast switching: 25 ns t_{ON}
- Low charge injection Q_{INJ}: 9 pC
- Low power consumption: < 1 μW
- SC-70 5-lead package

BENEFITS

- High accuracy
- High bandwidth
- TTL and low voltage logic compatibility
- Low power consumption
- Reduced PCB space

APPLICATIONS

- Mixed signal routing
- · Portable and battery operated systems
- Low voltage data acquisition
- Modems
- PCMCIA cards

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

SC-70-5L COM 5 V+ NO GND IN DG2715 Top View Device Marking: F7 SC-70-5L COM V+ 5 NC GND IN 3 DG2716 Top View Device Marking: F6

TRUTH TABLE (DG2715)				
Logic	Switch			
0	OFF			
1	ON			

TRUTH TABLE (DG2716)					
Logic	Switch				
0	ON				
1	OFF				

ORDERING INFORMATION					
Temp. Range	Package	Part Number			
- 40 °C to 85 °C	SC70-5	DG2715DL-T1-E3			
	3070-5	DG2716DL-T1-E3			

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ABSOLUTE MAXIMUM RATINGS

Parameter	Limit	Unit V		
Reference V+ to GND	- 0.3 to + 4			
IN, COM, NC, NO ^a		- 0.3 to (V+ + 0.3 V)	V	
Continuous Current (NO, NC and COM	± 200	mA		
Peak Current (Pulsed at 1 ms, 10 % du	uty cycle)	± 300	ША	
Storage Temperature	(D Suffix)	- 65 to 150	°C	
Power Dissipation (Packages) ^b	5-Pin SC-70 ^c	250	mW	

Notes:

a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

b. All leads welded or soldered to PC board.

c. Derate 3.1 mW/°C above 70 °C.

		Test Conditions Otherwise Unless Specified		Limits - 40 °C to 85 °C			
Parameter	Symbol	V+ = 1.8 V, \pm 10 %, V $_{\rm IN}$ = 0.4 V or 1.0 V $^{\rm e}$	Temp. ^a	Min. ^b	Typ. ^c	Max. ^b	Uni
Analog Switch			•		•	•	
Analog Signal Range ^d	V _{NO} , V _{NC} , V _{COM}		Full	0		V+	V
On-Resistance	R _{ON}	V+ = 1.8 V, V _{COM} = 0.9 V I _{NO} , I _{NC} = 10 mA	Room Full ^d		0.7	1.5 2.0	Ω
Switch Off Leakage Current ^f	I _{NO(off)} I _{NC(off)}	V+ = 2.0 V, V _{NO} , V _{NC} = 0.2 V/1.8 V, V _{COM} = 1.8 V/0.2 V	Room Full ^d Room	- 1 - 10 - 1		1 10 1	
	I _{COM(off)}		Full ^d	- 10		10	nA
Channel-On Leakage Current ^f	I _{COM(on)}	V+ = 2.0 V, V _{NO} , V _{NC} = V _{COM} = 0.2 V/1.8 V	Room Full ^d	- 1 - 10		1 10	
Digital Control							
Input High Voltage	V _{INH}		Full	1.0			v
Input Low Voltage	V _{INL}		Full			0.4	ľ
Input Capacitance ^d	C _{in}		Full		4		pF
Input Current ^f	$I_{\rm INL}$ or $I_{\rm INH}$	V _{IN} = 0 or V+	Full	- 1		1	μA
Dynamic Characteristics							
Turn-On Time ^d	t _{ON}	$V_{NO} \text{ or } V_{NC}$ = 1.5 V, R_L = 50 Ω , C_L = 35 pF	Room Full ^d		24	36	ns
Turn-Off Time ^d	t _{OFF}	figures1 and 2	Room Full ^d		21	33	
Charge Injection ^d	Q _{INJ}	C_{L} = 1 nF, V_{GEN} = 0 V, R_{GEN} = 0 $\Omega,$ figure 3	Room		13		pC
Off-Isolation ^d	OIRR	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 1 MHz$	Room		- 57		dB
N _O , N _C Off Capacitance ^d	C _{NO(off)} C _{NC(off)}	V _{IN} = 0 or V+, f = 1 MHz	Room		78		pF
Channel-On Capacitance ^d	C _{ON}		Room		93		



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		Test Conditions Otherwise Unless Specified		Limits - 40 °C to 85 °C				
Parameter	Symbol	V+ = 3 V, \pm 10 %,V _{IN} = 0.5 V or 1.4 V ^e	Temp. ^a	Min. ^b	Typ. ^c	Max. ^b	Unit	
Analog Switch								
Analog Signal Range ^d	V _{NO} , V _{NC} , V _{COM}		Full	0		V+	v	
On-Resistance	R _{ON}	V+ = 2.7 V, V _{COM} = 1.5 V I _{NO} , I _{NC} = 100 mA	Room Full		0.4	0.6	Ω	
R _{ON} Flatness	R _{ON} Flatness	V+ = 2.7 V, V _{COM} = 0.6 V, 1.5 V, 2.1 V I _{NO} , I _{NC} = 100 mA	Room		0.1	0.2		
Switch Off Leakage Current	I _{NO(off)} I _{NC(off)}	$V_{\rm NO}, V_{\rm NC} = 0.3 \text{ V/3 V}, V_{\rm COM} = 3 \text{ V/0.3 V}$		- 1 - 10		1 10	nA	
	I _{COM(off)}			- 1 - 10		1 10		
Channel-On Leakage Current	I _{COM(on)}	V+ = 3.3 V, V _{NO} , V _{NC} = V _{COM} = 0.3 V/3 V	Room Full	- 1 - 10		1 10		
Digital Control								
Input High Voltage	V _{INH}		Full	1.4			v	
Input Low Voltage	V _{INL}		Full			0.5	v	
Input Capacitance ^d	C _{in}		Full		5		pF	
Input Current	I _{INL} or I _{INH}	V _{IN} = 0 or V+	Full	- 1		1	μA	
Dynamic Characteristics								
Turn-On Time	t _{ON}	V_{NO} or V_{NC} = 1.5 V, R_L = 50 Ω , C_L = 35 pF	Room Full		17	29	ns	
Turn-Off Time	t _{OFF}	Figure 1	Room Full		14	26	_	
Charge Injection ^d	Q _{INJ}	$C_L = 1 \text{ nF}, V_{GEN} = 0 \text{ V}, R_{GEN} = 0 \Omega$, figure 3	Room		9		рС	
Off-Isolation ^d	OIRR	R_L = 50 Ω, C_L = 5 pF, f = 1 MHz	Room		- 57		dB	
NO, NC Off Capacitance ^d	C _{NO(off)} C _{NC(off)}	V _{IN} = 0 or V+, f = 1 MHz			72		pF	
Channel-On Capacitance ^d	C _{ON}		Room		92		1	
Power Supply	•		<u>. </u>					
Power Supply Range	V+			1.5		3.6	V	
Power Supply Current	I+	V+ = 3.6 V, V _{IN} = 0 or V+			0.01	1.0	μA	

Notes:

a. Room = 25 °C, Full = as determined by the operating suffix.

b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

c. Typical values are for design aid only, not guaranteed nor subject to production testing.

d. Guarantee by design, nor subjected to production test.

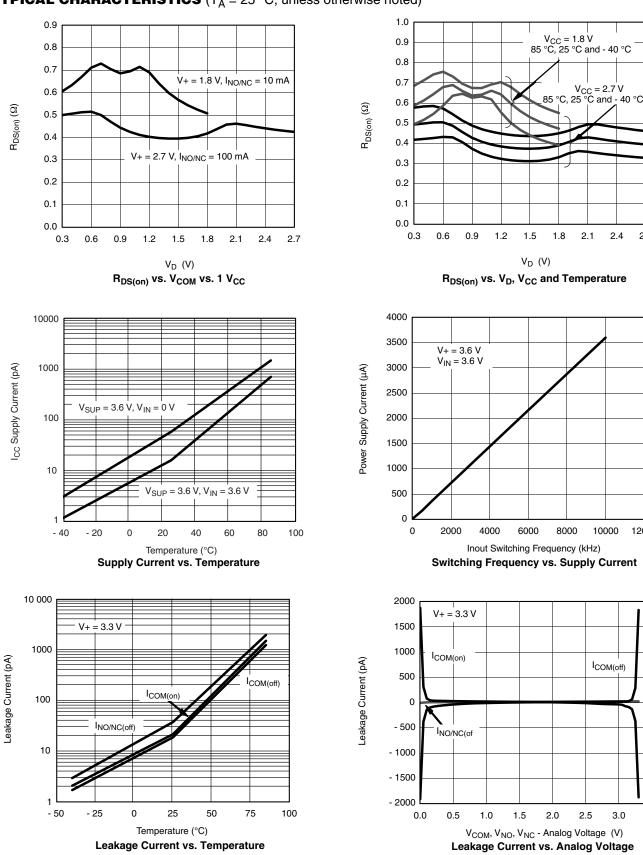
e. V_{IN} = input voltage to perform proper function.

f. Guaranteed by 3 V leakage testing, not production tested.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



3.0

3.5



2.4

10000

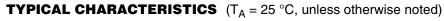
I_{COM(off)}

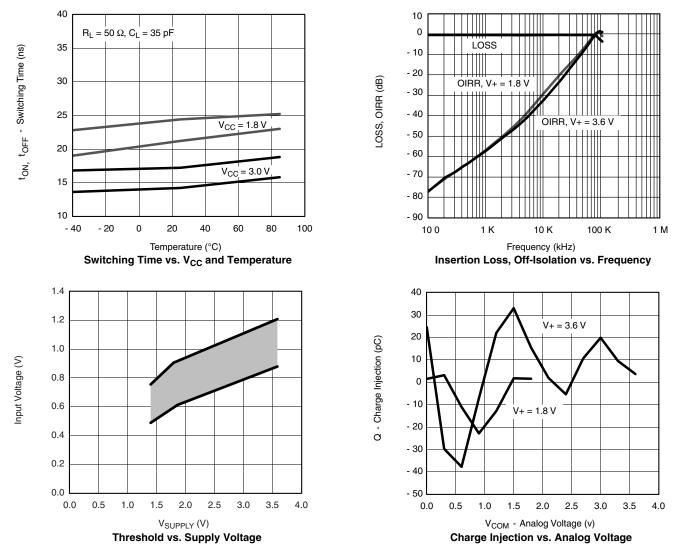
12000

2.7



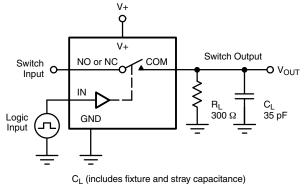
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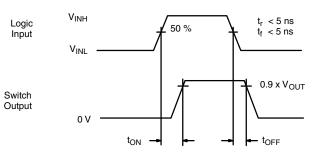


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TEST CIRCUITS

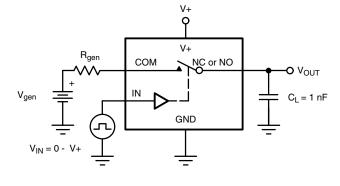


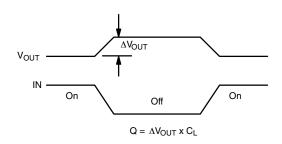
$$V_{OUT} = V_{COM} \left(\frac{R_L}{R_L + R_{ON}} \right)$$



Logic "1" = Switch On Logic input waveforms inverted for switches that have the opposite logic sense.







IN depends on switch configuration: input polarity determined by sense of switch.

Figure 2. Charge Injection





TEST CIRCUITS

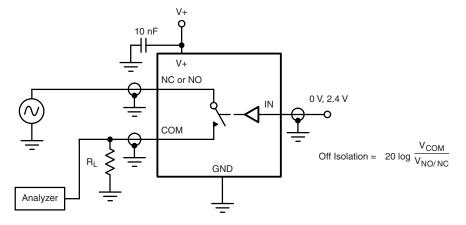


Figure 3. Off-Isolation

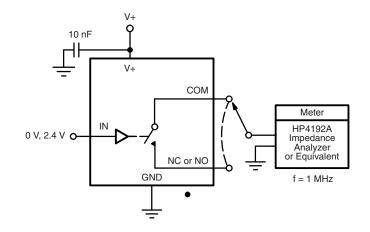


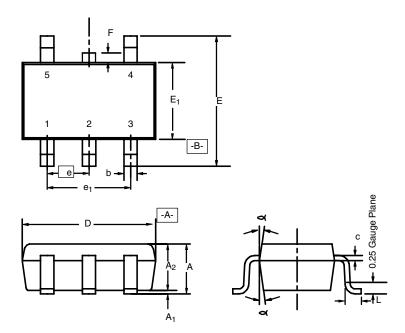
Figure 4. Channel Off/On Capacitance

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?72740.



Package Information Vishay Siliconix

SC-70: 5-LEAD



	MIL	LIMET	ERS	INCHES			
Dim	Min	Nom	Max	Min	Nom	Max	
Α	0.90	-	1.10	0.035	-	0.043	
A 1	Ι	-	0.10	-	-	0.004	
A ₂	0.80	-	1.00	0.031	-	0.039	
b	0.15	-	0.30	0.006	-	0.012	
С	0.10	-	0.25	0.004	-	0.010	
D	1.80	2.00	2.20	0.071	0.079	0.087	
Е	1.80	2.10	2.40	0.071	0.083	0.094	
E ₁	1.15	1.25	1.35	0.045	0.049	0.053	
е		0.65BSC		0.026BSC			
e ₁	1.20	1.30	1.40	0.047	0.051	0.055	
F	0	-	0.15	0	-	0.006	
L	0.10	0.20	0.30	0.004	0.008	0.012	
a	7°Nom				7°Nom		



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